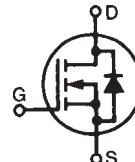


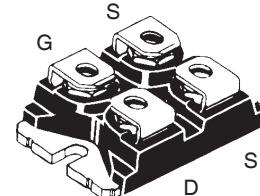
**GigaMOS™ HiperFET™  
Power MOSFET**
**IXFN140N25T**

**$V_{DSS}$**  = **250V**  
 **$I_{D25}$**  = **120A**  
 **$R_{DS(on)}$**  ≤ **17mΩ**  
 **$t_{rr}$**  ≤ **200ns**



N-Channel Enhancement Mode  
Avalanche Rated  
Fast Intrinsic Diode

**miniBLOC**  
 E153432



Symbol	Test Conditions	Maximum Ratings		
$V_{DSS}$	$T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$	250	V	
$V_{DGR}$	$T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$ , $R_{GS} = 1\text{M}\Omega$	250	V	
$V_{GSS}$	Continuous	±20	V	
$V_{GSM}$	Transient	±30	V	
$I_{D25}$	$T_C = 25^\circ\text{C}$	120	A	
$I_{DM}$	$T_C = 25^\circ\text{C}$ , Pulse Width Limited by $T_{JM}$	400	A	
$I_A$	$T_C = 25^\circ\text{C}$	40	A	
$E_{AS}$	$T_C = 25^\circ\text{C}$	3	J	
$P_D$	$T_C = 25^\circ\text{C}$	690	W	
$dv/dt$	$I_S \leq I_{DM}$ , $V_{DD} \leq V_{DSS}$ , $T_J \leq 150^\circ\text{C}$	20	V/ns	
$T_J$		-55 ... +150	°C	
$T_{JM}$		150	°C	
$T_{stg}$		-55 ... +150	°C	
$V_{ISOL}$	50/60 Hz, RMS	2500	V~	
	$I_{ISOL} \leq 1\text{mA}$	3000	V~	
$T_L$	1.6mm (0.062 in.) from Case for 10s	300	°C	
$T_{SOLD}$	Plastic Body for 10s	260	°C	
$M_d$	Mounting Torque	1.5/13	Nm/lb.in.	
	Terminal Connection Torque	1.3/11.5	Nm/lb.in.	
<b>Weight</b>		30	g	

Symbol	Test Conditions ( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified)	Characteristic Values		
		Min.	Typ.	Max.
$BV_{DSS}$	$V_{GS} = 0\text{V}$ , $I_D = 3\text{mA}$	250		V
$V_{GS(th)}$	$V_{DS} = V_{GS}$ , $I_D = 4\text{mA}$	2.5		V
$I_{GSS}$	$V_{GS} = \pm 20\text{V}$ , $V_{DS} = 0\text{V}$			$\pm 200$ nA
$I_{DSS}$	$V_{DS} = V_{DSS}$ , $V_{GS} = 0\text{V}$			$50 \mu\text{A}$ 3 mA
$R_{DS(on)}$	$V_{GS} = 10\text{V}$ , $I_D = 60\text{A}$ , Note 1			17 mΩ

**Features**

- International Standard Package
- miniBLOC, with Aluminium Nitride Isolation
- High Current Handling Capability
- Fast Intrinsic Diode
- Low  $R_{DS(ON)}$
- Avalanche Rated

**Advantages**

- Easy to Mount
- Space Savings
- High Power Density

**Applications**

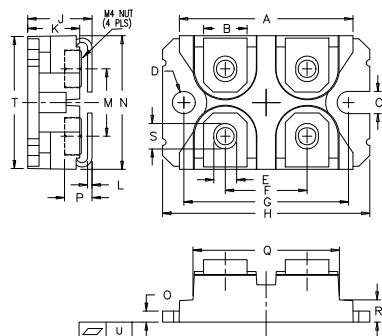
- DC-DC Converters
- Battery Chargers
- Switch-Mode and Resonant-Mode Power Supplies
- DC Choppers
- AC Motor Drives
- Uninterruptible Power Supplies
- High Speed Power Switching Applications

Symbol	Test Conditions ( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified)	Characteristic Values		
		Min.	Typ.	Max.
$g_{fs}$	$V_{DS} = 10\text{V}$ , $I_D = 60\text{A}$ , Note 1	80	135	S
$C_{iss}$			19	nF
$C_{oss}$			1500	pF
$C_{rss}$			185	pF
$t_{d(on)}$			33	ns
$t_r$			29	ns
$t_{d(off)}$			92	ns
$t_f$			22	ns
$Q_{g(on)}$			255	nC
$Q_{gs}$			90	nC
$Q_{gd}$			62	nC
$R_{thJC}$			0.18	$^\circ\text{C}/\text{W}$
$R_{thCS}$		0.05		$^\circ\text{C}/\text{W}$

**Source-Drain Diode**

Symbol	Test Conditions ( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified)	Characteristic Values		
		Min.	Typ.	Max.
$I_s$	$V_{GS} = 0\text{V}$		140	A
$I_{SM}$	Repetitive, Pulse Width Limited by $T_{JM}$		560	A
$V_{SD}$	$I_F = 60\text{A}$ , $V_{GS} = 0\text{V}$ , Note 1		1.3	V
$t_{rr}$			200	ns
$I_{RM}$			A	
$Q_{RM}$	$I_F = 70\text{A}$ , $V_{GS} = 0\text{V}$ -di/dt = 100A/ $\mu\text{s}$ $V_R = 75\text{V}$	9.3	600	nC

Note 1. Pulse test,  $t \leq 300\mu\text{s}$ , duty cycle,  $d \leq 2\%$ .

**SOT-227B (IXFN) Outline**

(M4 screws (4x) supplied)

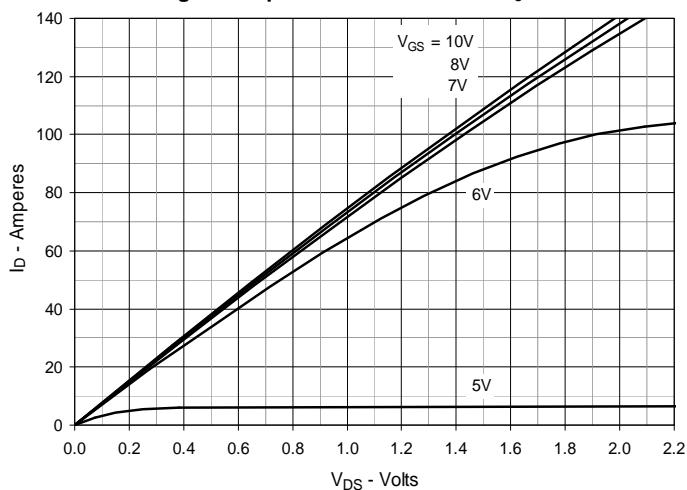
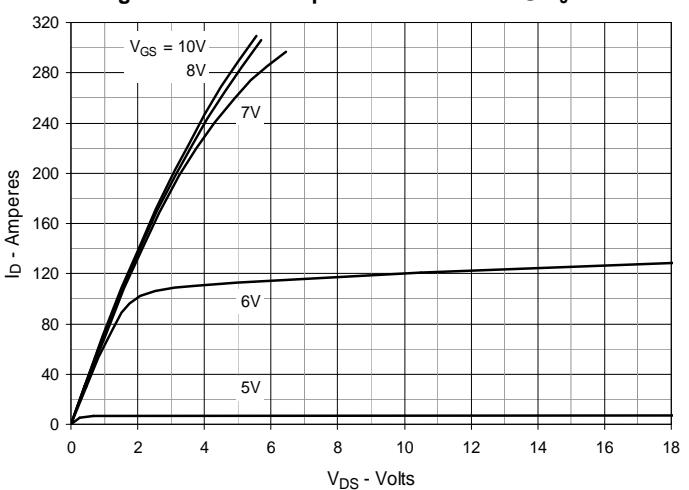
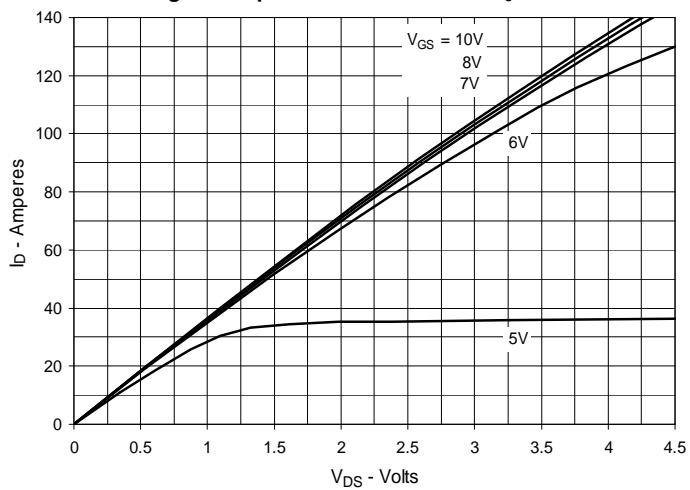
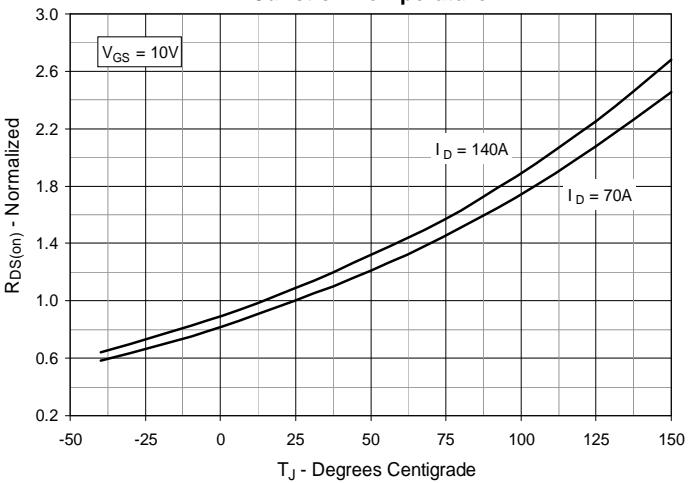
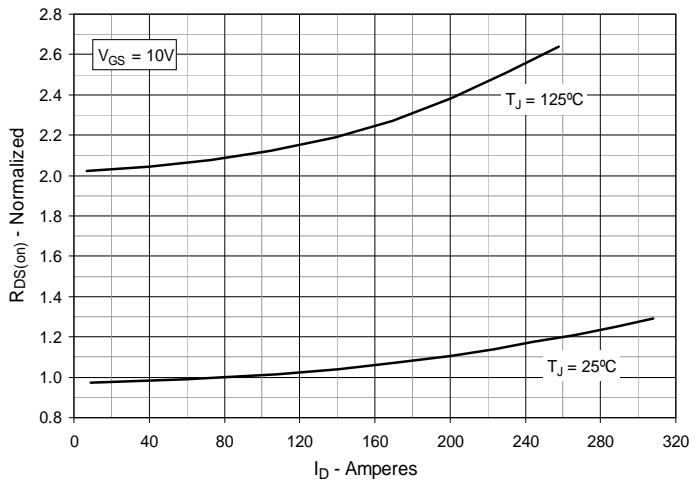
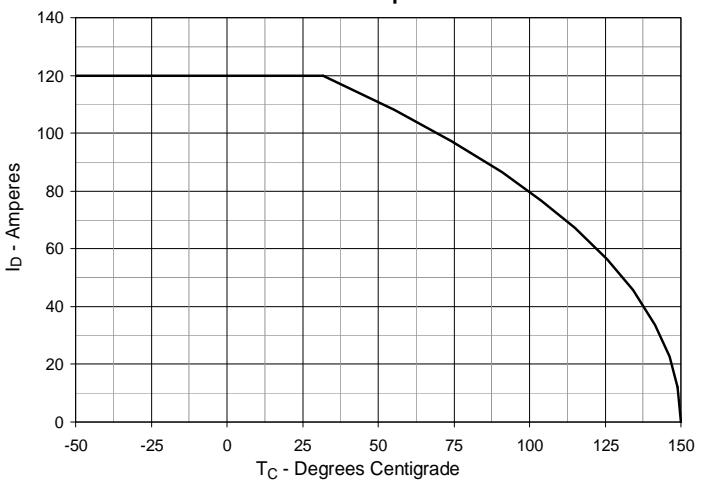
SYM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	1.240	1.255	31.50	31.88
B	.307	.323	7.80	8.20
C	.161	.169	4.09	4.29
D	.161	.169	4.09	4.29
E	.161	.169	4.09	4.29
F	.587	.595	14.91	15.11
G	1.186	1.193	30.12	30.30
H	1.496	1.505	38.00	38.23
J	.460	.481	11.68	12.22
K	.351	.378	8.92	9.60
L	.030	.033	0.76	0.84
M	.496	.506	12.60	12.85
N	.990	1.001	25.15	25.42
O	.078	.084	1.98	2.13
P	.195	.235	4.95	5.97
Q	1.045	1.059	26.54	26.90
R	.155	.174	3.94	4.42
S	.186	.191	4.72	4.85
T	.968	.987	24.59	25.07
U	-.002	.004	-0.05	0.1

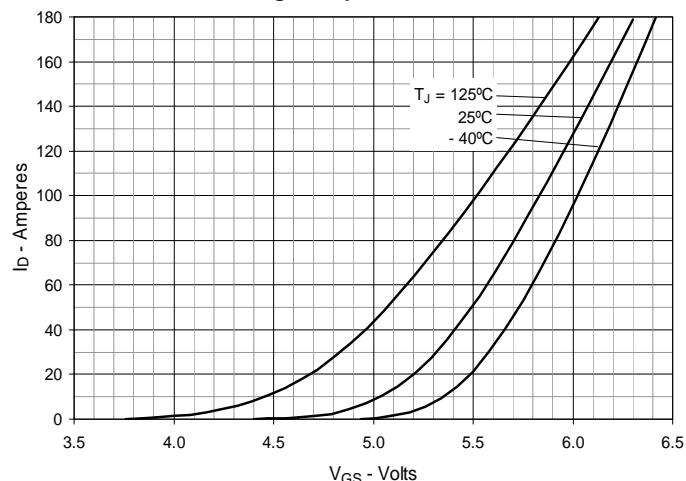
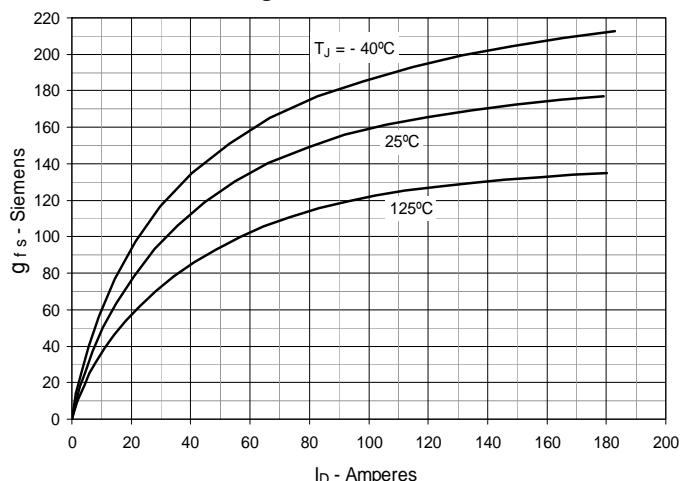
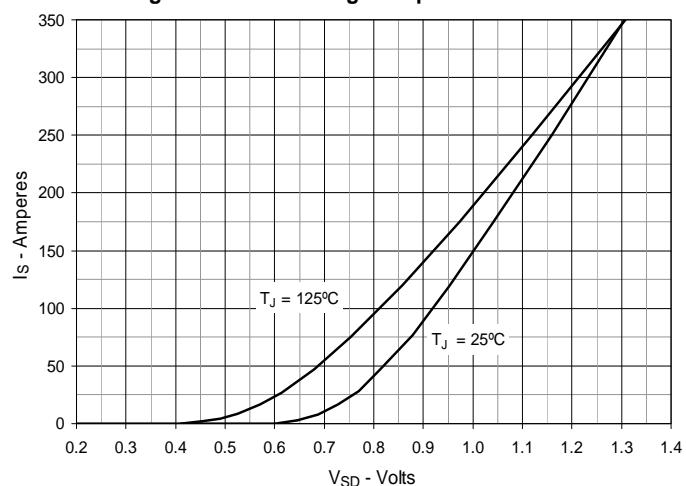
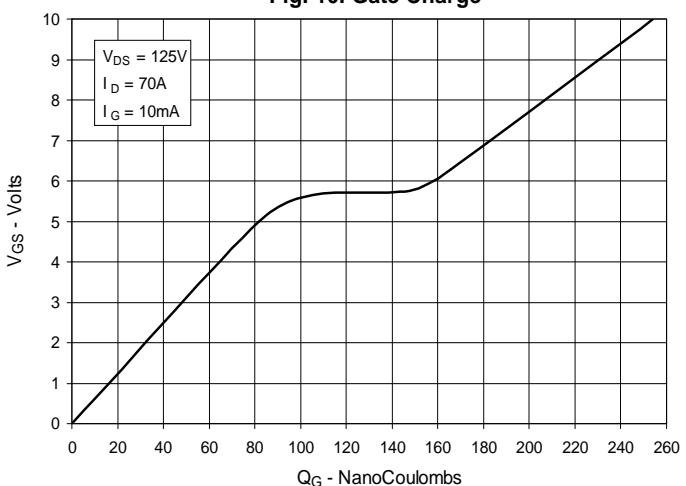
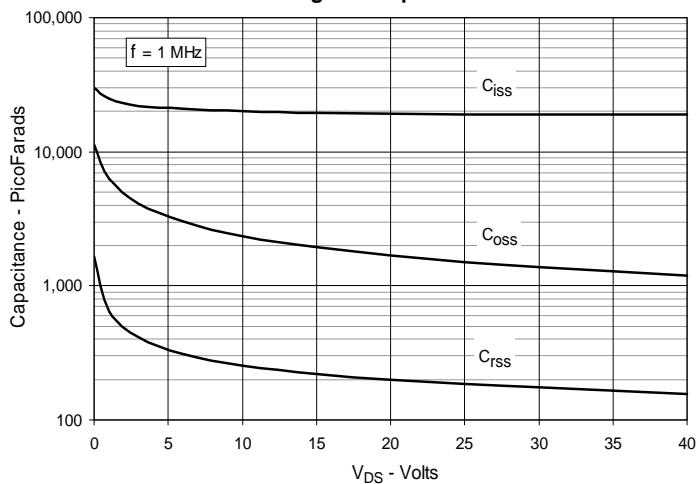
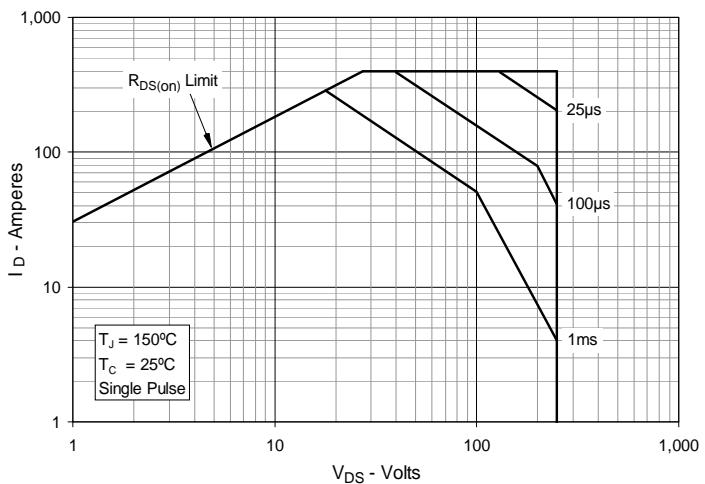
**ADVANCE TECHNICAL INFORMATION**

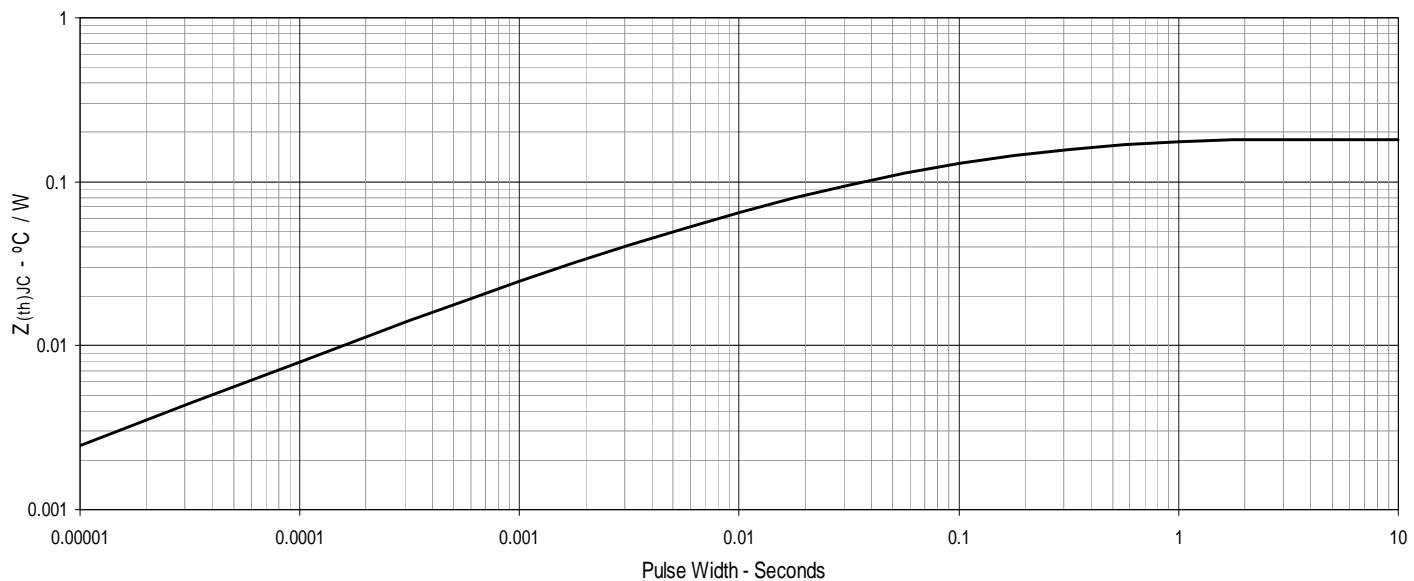
The product presented herein is under development. The Technical Specifications offered are derived from a subjective evaluation of the design, based upon prior knowledge and experience, and constitute a "considered reflection" of the anticipated result. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.

IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents: 4,835,592 4,931,844 5,049,961 5,237,481 6,162,665 6,404,065 B1 6,683,344 6,727,585 7,005,734 B2 7,157,338B2 4,850,072 5,017,508 5,063,307 5,381,025 6,259,123 B1 6,534,343 6,710,405 B2 6,759,692 7,063,975 B2 4,881,106 5,034,796 5,187,117 5,486,715 6,306,728 B1 6,583,505 6,710,463 6,771,478 B2 7,071,537

**Fig. 1. Output Characteristics @  $T_J = 25^\circ\text{C}$** **Fig. 2. Extended Output Characteristics @  $T_J = 25^\circ\text{C}$** **Fig. 3. Output Characteristics @  $T_J = 125^\circ\text{C}$** **Fig. 4.  $R_{DS(on)}$  Normalized to  $I_D = 70\text{A}$  Value vs. Junction Temperature****Fig. 5.  $R_{DS(on)}$  Normalized to  $I_D = 70\text{A}$  Value vs. Drain Current****Fig. 6. Maximum Drain Current vs. Case Temperature**

**Fig. 7. Input Admittance****Fig. 8. Transconductance****Fig. 9. Forward Voltage Drop of Intrinsic Diode****Fig. 10. Gate Charge****Fig. 11. Capacitance****Fig. 12. Forward-Bias Safe Operating Area**

**Fig. 13. Maximum Transient Thermal Impedance**



---

Disclaimer Notice - Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at [www.littelfuse.com/disclaimer-electronics](http://www.littelfuse.com/disclaimer-electronics).

# X-ON Electronics

Largest Supplier of Electrical and Electronic Components

***Click to view similar products for MOSFET category:***

***Click to view products by IXYS manufacturer:***

Other Similar products are found below :

[614233C](#) [648584F](#) [MCH3443-TL-E](#) [MCH6422-TL-E](#) [FDPF9N50NZ](#) [FW216A-TL-2W](#) [FW231A-TL-E](#) [APT5010JVR](#) [NTNS3A92PZT5G](#)  
[IRF100S201](#) [JANTX2N5237](#) [2SK2464-TL-E](#) [2SK3818-DL-E](#) [FCA20N60\\_F109](#) [FDZ595PZ](#) [STD6600NT4G](#) [FSS804-TL-E](#) [2SJ277-DL-E](#)  
[2SK1691-DL-E](#) [2SK2545\(Q,T\)](#) [405094E](#) [423220D](#) [MCH6646-TL-E](#) [TPCC8103,L1Q\(CM](#) [367-8430-0972-503](#) [VN1206L](#) [424134F](#)  
[026935X](#) [051075F](#) [SBVS138LT1G](#) [614234A](#) [715780A](#) [NTNS3166NZT5G](#) [751625C](#) [873612G](#) [IRF7380TRHR](#) [IPS70R2K0CEAKMA1](#)  
[RJK60S3DPP-E0#T2](#) [RJK60S5DPK-M0#T0](#) [APT5010JVFR](#) [APT12031JFLL](#) [APT12040JVR](#) [DMN3404LQ-7](#) [NTE6400](#) [JANTX2N6796U](#)  
[JANTX2N6784U](#) [JANTXV2N5416U4](#) [SQM110N05-06L-GE3](#) [SIHF35N60E-GE3](#) [2SK2614\(TE16L1,Q\)](#)